# NPN Silicon Epitaxial Transistor

This NPN Silicon Epitaxial Transistor is designed for use in low voltage, high current applications. The device is housed in the SOT-223 package, which is designed for medium power surface mount applications.

### **Features**

- High Current:  $I_C = 1.0 A$
- The SOT-223 Package Can Be Soldered Using Wave or Reflow
- SOT-223 package ensures level mounting, resulting in improved thermal conduction, and allows visual inspection of soldered joints.
   The formed leads absorb thermal stress during soldering, eliminating the possibility of damage to the die
- The PNP Complement is BCP69T1
- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*

### **MAXIMUM RATINGS** (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	20	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	25	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current	I <sub>C</sub>	1.0	Adc
Total Power Dissipation @ T <sub>A</sub> = 25°C (Note 1) Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to 150	°C

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (Surface Mounted)	$R_{\theta JA}$	83.3	°C/W
Lead Temperature for Soldering, 0.0625 in from case Time in Solder Bath	TL	260 10	°C Sec

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Device mounted on a glass epoxy printed circuit board 1.575 in. x 1.575 in. x 0.059 in.; mounting pad for the collector lead min. 0.93 sq. in.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



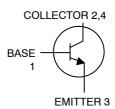
## ON Semiconductor®

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# MEDIUM POWER NPN SILICON HIGH CURRENT TRANSISTOR SURFACE MOUNT



SOT-223 CASE 318E STYLE 1



#### **MARKING DIAGRAM**



CA = Specific Device Code

A = Assembly Location Y = Year

W = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
BCP68T1G	SOT-223 (Pb-Free)	1,000/Tape & Reel
SBCP68T1G	SOT-223 (Pb-Free)	1,000/Tape & Reel
BCP68T3G	SOT-223 (Pb-Free)	4,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				•
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 100 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CES</sub>	25	-	_	Vdc
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)		20	-	-	Vdc
Emitter–Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	5.0	-	-	Vdc
Collector-Base Cutoff Current (V <sub>CB</sub> = 25 Vdc, I <sub>E</sub> = 0)		-	-	10	μAdc
Emitter–Base Cutoff Current ( $V_{EB} = 5.0 \text{ Vdc}$ , $I_{C} = 0$ )	I <sub>EBO</sub>	-	-	10	μAdc
ON CHARACTERISTICS					
DC Current Gain $ \begin{aligned} &(I_C=5.0 \text{ mAdc, V}_{CE}=10 \text{ Vdc}) \\ &(I_C=500 \text{ mAdc, V}_{CE}=1.0 \text{ Vdc}) \\ &(I_C=1.0 \text{ Adc, V}_{CE}=1.0 \text{ Vdc}) \end{aligned} $	h <sub>FE</sub>	50 85 60	- - -	- 375 -	-
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 1.0 Adc, I <sub>B</sub> = 100 mAdc)		-	_	0.5	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 1.0 Vdc)	V <sub>BE(on)</sub>	-	_	1.0	Vdc
DYNAMIC CHARACTERISTICS					
Current-Gain - Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 5.0 Vdc)	f <sub>T</sub>	-	60	_	MHz

### TYPICAL ELECTRICAL CHARACTERISTICS

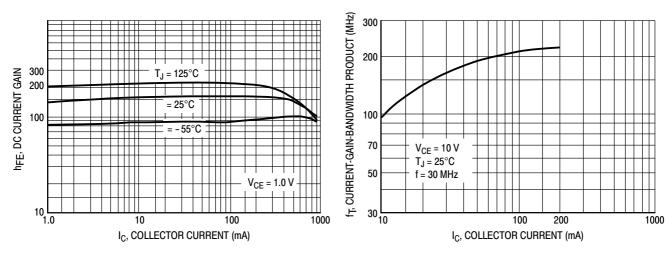
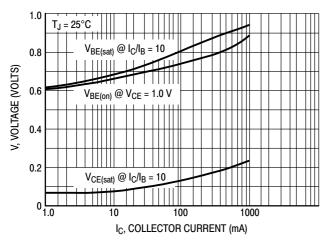


Figure 1. DC Current Gain

Figure 2. Current-Gain-Bandwidth Product

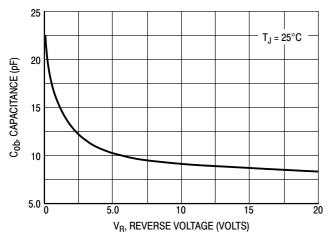
### TYPICAL ELECTRICAL CHARACTERISTICS



70 T<sub>J</sub> = 25°C T 70 40 30 0 1.0 2.0 3.0 4.0 5.0 V<sub>R</sub>, REVERSE VOLTAGE (VOLTS)

Figure 3. "On" Voltage

Figure 4. Capacitance



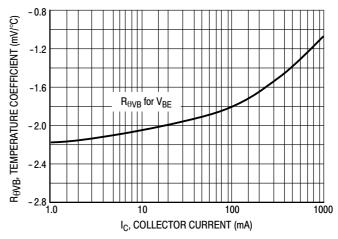


Figure 5. Capacitance

Figure 6. Base-Emitter Temperature Coefficient

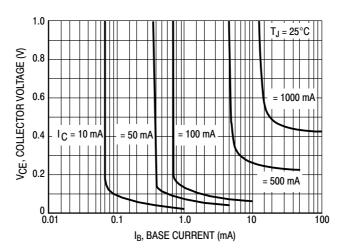
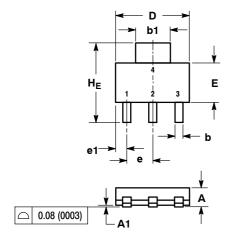
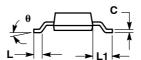


Figure 7. Saturation Region

#### PACKAGE DIMENSIONS

### SOT-223 (TO-261) CASE 318E-04 ISSUE N





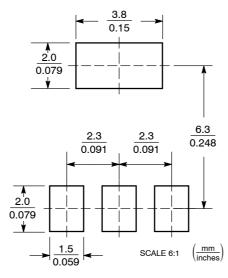
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M,
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	_	10°

STYLE 1:

- PIN 1. BASE
- COLLECTOR
- EMITTER COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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